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*Complete if Known*

Application Number	10/519,084
Confirmation Number	7332
Filing Date	December 23, 2004
First Named Inventor	Heiji WATANABE
Art Unit	2822
Examiner Name	Tsz K. CHIU

Attorney Docket Number Q85504

**U.S. PATENT DOCUMENTS**

Examiner Initials*	Cite No. <sup>1</sup>	Document Number		Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document
		Number	Kind Code <sup>2</sup> (if known)		
		US			

**FOREIGN PATENT DOCUMENTS**

Examiner Initials*	Cite No. <sup>1</sup>	Foreign Patent Document			Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Translation <sup>6</sup>
		Country Code <sup>3</sup>	Number <sup>4</sup>	Kind Code <sup>5</sup> (if known)			
		JP	2000-195856	A	07-14-2000		
		JP	2005-534163	A	11-10-2005		
		JP	2003-282873	A	10-03-2003		
/TC/		JP	2003-8005	A	01-10-2003	Matsushita Electric Inc. Co. Ltd	
/TC/		JP	2000-3885	A	01-07-2000	Lucent Technology Inc.	

**NON PATENT LITERATURE DOCUMENTS**

Examiner Initials*	Cite No. <sup>1</sup>	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city, and/or country where published.	Translation <sup>6</sup>
/TC/		Hyungsuk Jung et al., Electrical and Reliability Characteristics of a n Ultrastrom TaOxNy Gate Dielectric Prepared by ND3 Annealing of Ta205, IEEE Electron Device Letters, December 2000, Vol. 21, No. 12, pp. 563-565	

Examiner Signature	/Tsz Chiu/ (01/20/2008)	Date Considered	01/20/2008
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